Silicon Controlled Rectifiers

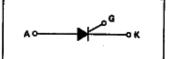
Reverse Blocking Triode Thyristors

... designed for industrial and consumer applications such as power supplies; battery chargers; temperature, motor, light and welder controls.

- Economical for a Wide Range of Uses
- High Surge Current ITSM = 350 Amp
- Practical Level Triggering and Holding Characteristics 4 and 5.2 mA (Typ) @ T_C = 25°C
- Rugged Construction in Either Pressfit, Stud or Isolated Stud Package

2N3870 thru 2N3873 2N3896 thru 2N3899 2N6171 thru 2N6174

SCRs 35 AMPERES RMS 100 thru 800 VOLTS





CASE 174-04 (TO-203) STYLE 1 2N3870 thru 2N3873



CASE 175-03 STYLE 1 2N3896 thru 2N3899



CASE 311-02 STYLE 1 (Stud Isolated) 2N6171 thru 2N6174

MAXIMUM RATINGS (TC = 100°C unless otherwise noted.)

| Rating | Symbol | Value | Unit |
|--|--------------------|--------------------------|------------------|
| *Peak Repetitive Forward or Reverse Blocking Voltage, Note 1 (T _J = -40 to +100°C, 1/2 Sine Wave, 50 to 400 Hz, Gate Open) 2N3870, 2N3896, 2N6171 2N3871, 2N3897, 2N6172 2N3872, 2N3898, 2N6173 2N3873, 2N3899, 2N6174 | VRRM or VDRM | 100 200 400 600 | Volts |
| *Peak Non-Repetitive Forward or Reverse Blocking Voltage (t ≤ 5 ms) 2N3870, 2N3896, 2N6171 2N3871, 2N3897, 2N6172 2N3872, 2N3898, 2N6173 2N3873, 2N3899, 2N6174 | VRSM or VDSM | 150 330 660 700 | Volts |
| *Average On-State Current, Note 2 {T _C = -40 to +65°C) {T _C = +85°C} | IT(AV) | 22 11 | Amps |
| *Peak Non-Repetitive Surge Current (One cycle, 60 Hz) (T _C = +65°C) | [[] TSM | 350 | Amps |
| Circuit Fusing (T _C = -40 to +100°C) (t = 1 to 8.30 ms) | l ² t | 510 | A ² s |

Indicates JEDEC Registered Data,

Notes: 1. Ratings apply for zero or negative gate voltage. Devices shall not have a positive bias applied to the gate concurrently with a negative potential on the anode. Devices should not be tested with a constant current source for forward or reverse blocking capability such that the voltage applied exceeds the rated blocking voltage.

2. Isolated stud devices must be derated an additional 10 percent.

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2N3870 thru 2N3873 • 2N3896 thru 2N3899 • 2N6171 thru 2N6174

MAXIMUM RATINGS (T_C = 100°C unless otherwise noted.)

| Rating | Symbol | Value | Unit | |
|---------------------------------------|------------------|-------------|---------|--|
| *Peak Gate Power | PGM | 20 | Watts | |
| *Average Gate Power | PG(AV) | 0.5 | Watt | |
| *Peak Forward Gate Current | 1 _{GM} | 2 | Amps | |
| Peak Gate Voltage | VGM | 10 | Voits | |
| *Operating Junction Temperature Range | TJ | -40 to +100 | °C | |
| *Storage Temperature Range | T _{stg} | -40 to +150 | °C | |
| Stud Torque | | 30 | in. lb. | |

^{*}Indicates JEDEC Registered Data.

*THERMAL CHARACTERISTICS

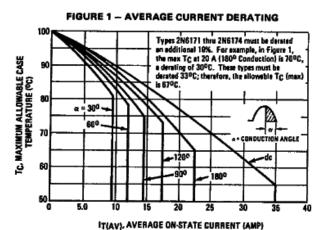
| Characteristic | Symbol | Max | Unit |
|--|--------|-----|------|
| Thermal Resistance, Junction to Case 2N3870 thru 2N3873, 2N3896 thru 2N3899 2N6171 thru 2N6174 | Røjc | 0.9 | °C/W |

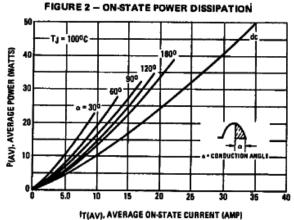
findicates JEDEC Registered Data.

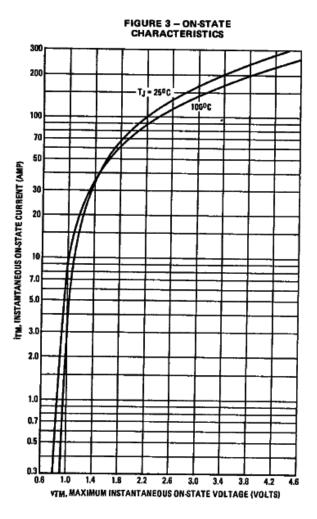
ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

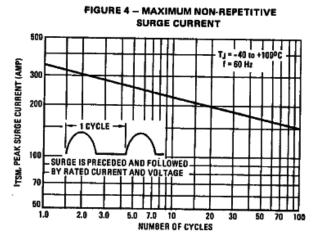
| Characteristic | Symbol | Min | Тур | Max ' | Unit |
|--|-----------------|-----|-------------|--------------------------|----------|
| *Peak Forward or Reverse Blocking Current (Rated V _{DRM} or V _{RRM} , gate open, T _J = 100°C) 2N3870, 2N3896, 2N6171 2N3871, 2N3897, 2N6172 2N3872, 2N3898, 2N6173 2N3873, 2N3899, 2N6174 (Rated V _{DRM} or V _{RRM} , gate open, T _J = 25°C) All Devices | IDRM, IRRM | | 1 1 1 | 2 2.5 3 4 10 | mA μA |
| *Peak On-State Voltage (ITM = 69 A Peak) | V _{TM} | _ | 1.5 | 1.85 | Volts |
| *Gate Trigger Current (Continuous dc) $^*T_C = -40^{\circ}C$ $(V_D = 12 \text{ V, R}_L = 24 \text{ ohms})$ $^*T_C = 25^{\circ}C$ | fGT . | = | 9 | 80 40 | mA |
| *Gate Trigger Voltage (Continuous dc) $^*T_C = -40^{\circ}C$ $\{V_D = q2 \text{ V, } R_L = 24 \text{ ohms}\}$ $^*T_C = 25^{\circ}C$ | V _{GT} | = | 0.9 0.69 | 3 1.6 | Volts |
| *Holding Current (Gate Open) | lн | = | 14 5.2 | 90 50 | mA |
| *Gate Controlled Turn-On Time (t _d + t _r) (I _{TM} = 41 Adc, V _D = rated V _{DRM} , I _{GT} = 40 mAdc, Rise Time ≤ 0.05 μs, Pulse Width = 10 μs) | ^t gt | _ | _ | 1.5 | μş |
| Circuit Commutated Turn-Off Time (I _{TM} = 10 A, I _R = 10 A) (I _{TM} = 10 A, I _R = 10 A, T _C = 100°C) | tq | _ | 25 35 | _ | μ\$ |
| Forward Voltage Application Rate (TC = 100°C, VD = Rated VDRM) | dv/dt | _ | 50 | | V/μs |

^{*}Indicates JEDEC Registered Data.





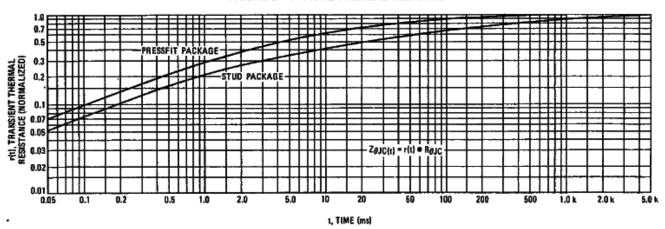




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2N3870 thru 2N3873 • 2N3896 thru 2N3899 • 2N6171 thru 2N6174

FIGURE 5 -- TYPICAL THERMAL RESPONSE





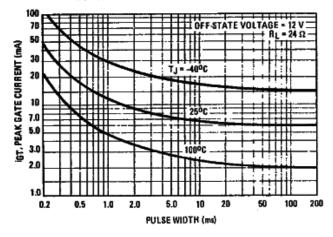


FIGURE 7 - GATE TRIGGER CURRENT

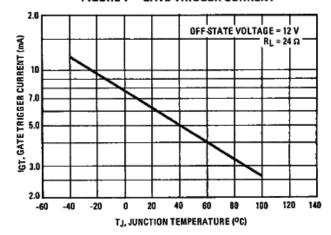


FIGURE 8 - GATE TRIGGER VOLTAGE

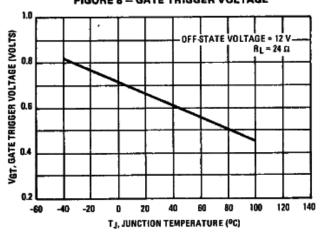


FIGURE 9 - HOLDING CURRENT

